# NSN 5961-00-904-4260

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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.400 inches and 0.420 inches

## **Overall Diameter:**

Between 0.760 inches and 0.770 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

Features Provided:

## Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

65.0 breakdown voltage, collector-to-base, emitter open and 55.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown

voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 7.00 amperes source cutoff current and 15.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

117.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

2 pin and 1 case

## **Specification Data:**

80131-release4716 professional/industrial association specification

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

## Fiig:

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